Phase equilibria in the BaO-MgO-Ta₂O₅ system

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We report on the phase relation in the BaO–MgO–Ta $_2O_5$ system equilibrated at 1450 °C. We found three ternary phases, namely 3:1:1 perovskite Ba $_3$ MgTa $_2O_9$, 9:1:7 TTB (tetragonal tungsten bronze)-type Ba $_9$ MgTa $_14O_{45}$ and 4:1:5 Ba $_4$ MgTa $_10O_{30}$ closely related to the tungsten bronze structure. Another ternary phase, Ba $_{10}$ Mg $_{0.25}$ Ta $_{7.9}O_{30}$, with a 10 layer hexagonal perovskite structure can be only obtained after equilibration at 1600 °C. MgO solubility in the TTB-like Ba $_4$ Ta $_{10}O_{29}$, BaTa $_4O_{11}$ and Ba $_{6.63}$ Ta $_{34.95}O_{95}$ does not exceed 2.0 mol%. Only the hexagonal polymorph of the BaTa $_2O_6$ phase was found along the Mg $_4$ Ta $_2O_9$ –BaTa $_2O_6$ join. Measurements of dielectric properties in the 20 Hz–2 MHz range revealed that Ba $_9$ MgTa $_{14}O_{45}$ has a dielectric constant of 99 with no frequency dispersion and low dielectric loss. We have also clarified several contradictory reports related to the ternary and binary phases in the BaO–MgO–Ta $_2O_5$ composition field.

1. Introduction

Low-loss dielectric ceramics are used as passive components in satellite and terrestrial wireless communication systems operating in the microwave (MW) frequency range. Utilization of these ceramics brings significant reduction in the weight and size of the MW electronic components. Driven by their exceptional technical importance, one of the most extensively studied compounds is a family of complex perovskites, namely $Ba_3M'M''_2O_9$ where M'=Mg, Zn, Co and M''=Nb, Ta.¹⁻⁷

Despite the high cost of tantalum, dielectric resonators based on Ba(Mg_{1/3}Ta_{2/3})O₃ will be viable in future applications as we are facing increasing shortages (and cost) of available electromagnetic frequency space. The Ba(Mg_{1/3}Ta_{2/3})O₃ ceramics have the lowest dielectric loss (*i.e.*, highest Q-factor) and therefore offer the most efficient utilization of the allocated electromagnetic frequency window, *i.e.*, they provide the largest number of communication channels within a fixed frequency band.

Preparation of high quality Ba(Mg_{1/3}Ta_{2/3})O₃ ceramics has proven to be challenging and only a few academic groups were able to achieve Q-factors exceeding 25 000 at 10 GHz. In contrast to the intuitive perception that the lowest dielectric loss should be attained in ideally stoichiometric Ba₃M'M"₂O₉ compounds, recent findings reveal that a small deviation from stoichiometry enhances the M':M" cation ordering and yields the highest Q-factors. 12,14 Even more surprising, the highest Q-factor in Ba(Co_{1/3}Nb_{2/3})O₃ is found beyond a single phase composition range. 15 In light of these new findings, it seems imperative to have a clear understanding of the phase equilibria in the BaO-MgO-Ta₂O₅ ternary system. Several ternary phases, including $Ba_{10}Mg_{0.25}Ta_{7.9}O_{30}$, $Ba_{9}MgTa_{14}O_{45}$, $Ba_{3}MgTa_{2}O_{9}$, $Ba_{8}Mg$ Ta₆O₂₄, Ba₄MgTa₁₀O₃₀, Ba₉Mg₄Ta₂₀O₆₃, reportedly exist in the BaO-MgO-Ta2O5 ternary system,16,19 yet their phase relationship has not been clarified. Although a tentative BaO-MgO-Ta₂O₅ phase diagram at 1450 °C has been proposed by Roth, ¹⁷ a complete phase equilibrium in the BaO-MgO-Ta₂O₅ composition field has never been reported. The present paper attempts to fill this gap.

2. Experimental

Chemical compositions in the BaO–MgO–Ta₂O₅ field were prepared from 99.99% BaCO₃ (Wako, Japan), 99.99% MgO and 99.9% Ta₂O₅ (Kanto Chem., Japan) precursors. Before preparation of the target compositions, the precursors were heattreated in air up to 900 °C to ensure that their composition corresponds to the chemical formula. In total, around 40 chemical compositions were analyzed in this study. The powders were mixed in ethanol medium using high density alumina mortar. After drying, the samples were pressed into pellets using a tungsten carbide (Fuji Die Co., Japan) die, and then fired at 1450 °C for 20 hours in 99.9% pure Al₂O₃ crucibles covered with lids. After firing, the samples were cooled to 900 °C within 1 hour and then withdrawn from the furnace and air cooled. In most cases, this procedure was repeated three times after which no changes in the powder X-ray diffraction patterns were observed.

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However, for compositions along the Mg₄Ta₂O₉-BaTa₂O₆ and the Ba₃MgTa₂O₉-Ba₅Ta₄O₁₅ tie lines the re-grinding and re-sintering were repeated four times to reach an equilibrium phase composition. In addition, selected compositions were sintered at 1600 °C for 5 hours. Phase identification and lattice parameters were examined with a Rigaku Ultima III X-ray diffractometer (Cu Ka radiation). Rietveld refinement of the crystal structures was performed using RIETAN 2000.20 Dielectric properties at room temperature were measured in the 20 Hz-2 MHz range using an Agilent E4980 Precision LCR Meter.

Results and discussion

The overall phase relationship between the BaO:MgO:Ta₂O₅ compositions equilibrated at 1450 °C is shown in Fig. 1. Although it carries some similarities with the tentative BaO-MgO-Ta₂O₅ phase diagram proposed by Roth¹⁷ one may also notice substantial differences. For samples equilibrated in air at 1450 °C there are only three ternary compounds. These include a 3:1:1 Ba₃MgTa₂O₉ perovskite, a 9:1:7 Ba₉MgTa₁₄O₄₅ phase with tetragonal tungsten bronze (TTB) structure²¹ and a 4:1:5 orthorhombic Ba₄MgTa₁₀O₃₀ phase.¹⁸

In the 9:1:7 phase Ba atoms occupy tetragonal and pentagonal channels whereas Mg and Ta atoms are randomly distributed inside the corner-sharing oxygen octahedra. This phase belongs

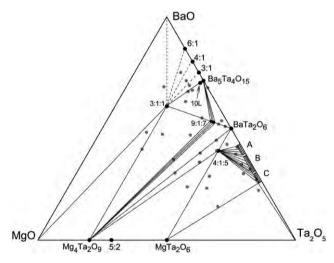


Fig. 1 Subsolidus phase diagram of BaO-MgO-Ta₂O₅ obtained for samples prepared in air at 1450 °C. The 10-layer (10L) hexagonal Ba₁₀Mg_{0.25}Ta_{7.9}O₃₀ phase included in the figure appears only at 1600 °C and cannot be obtained at 1450 °C. Grey dots are the compositions prepared in this study. Formulae and numbers designate distinct phases. At 1450 °C only three ternary compounds were identified, i.e., 3:1:1 = $Ba_{3}MgTa_{2}O_{9}$, 9:1:7 = $Ba_{9}MgTa_{14}O_{45}$ and 4:1:5 = $Ba_{4}MgTa_{10}O_{30}$. In agreement with ref. 31 we found that BaO-rich phases, such as 3:1, 4:1 and 6:1 along the BaO-Ta₂O₅ binary, are unstable at room temperature. The 3:1:1 phase forms tie lines with Mg₄Ta₂O₉ and 9:1:7 phases. Compositions along the Mg₄Ta₂O₉-BaTa₂O₆ join contain a hexagonal polymorph of the BaTa2O6 phase. Phases labeled A, B, and C are TTBtype compounds described in detail in ref. 31; $A = Ba_x Ta_{(10-2x)/5} [Ta_{10}O_{30}]$ where $3.40 \le x \le 3.93$, $B = Ba_v Ta_{(14-2v)/5}[Ta_{22}O_{62}]$ where $5.11 \le y \le 6.77$, $C = Ba_z Ta_{(18-2z)/5} [Ta_{34}O_{94}]$ where $6.17 \le z \le 7.42$.

to a large family of the A₆B₁₀O₃₀ TTB compounds intensively studied during the 'ferroelectric boom' in the second half of the last century.²² A number of the compounds in this family show ferroelectric properties including Nb analogues of the 9:1:7 phase, e.g., $Ba_9MgNb_{14}O_{45}$ ($T_C \approx 248 \text{ K}$) and $Sr_9MgNb_{14}O_{45}$ $(T_C \approx 283 \text{ K})^{23}$ In agreement with earlier reports,²³ we found that the TTB Ba₉MgTa₁₄O₄₅ phase is not exactly a point compound. It appears to have a finite solubility range of ca. 2–3 mol% extending along both sides of the 9:1:7 composition towards the Ba₃MgTa₂O₉ and BaTa₂O₆ end members. Rietveld refinement confirmed earlier reports that the TTB 9:1:7 compound is isostructural with the TTB BaTa₂O₆ polymorph²⁴ as well as with its reduced analogues, e.g., Ba₃Ta₅O₁₅ and Ba₃Nb₅O₁₅; all of them crystallize in the same P4/mbm space group.^{25,26} For initial refinement of the 9:1:7 phase we have used atomic coordinates of the tetragonal BaTa₂O₆ polymorph.²⁴ Table 1 shows lattice parameters of the 9:1:7 phase as a function of the BaO:MgO:Ta₂O₅ composition. The unit cell volume increases with an increase in the occupation of the Ta sites with slightly larger Mg2+ ions.

There are several important differences between this study and the BaO-MgO-Ta₂O₅ phase equilibria at 1450 °C reported by Roth.¹⁷ In contrast to ref. 17, we could not find a tie line between the MgO and the TTB 9:1:7 phase; neither we can confirm a join between MgO and BaTa₂O₆. Instead, we found that the Ba₃MgTa₂O₉ phase forms tie lines with the Mg₄Ta₂O₉ and TTB 9:1:7 phases. In fact, Ba₃MgTa₂O₉ is the only ternary phase that forms along the join between corundum-like Mg₄Ta₂O₉ and an unstable Ba₄Ta₂O₉. Furthermore, in contrast to ref. 17, we could not confirm the existence of the hexagonal 9:4:10 Ba₉Mg₄Ta₂₀O₆₃ phase along the Mg₄Ta₂O₉–BaTa₂O₆ line. All three intermediate compositions along the Mg₄Ta₂O₉–BaTa₂O₆ join turned out to be mixtures of the end members: $Mg_4Ta_2O_9$ (space group $P\bar{3}c1$) and a hexagonal polymorph of BaTa₂O₆ (space group *P6/mmm*).

A variety of layered hexagonal perovskites have been reported along the tie line connecting the 3:1:1 cubic perovskite Ba₃M'M"₂O₉ and 5-layer hexagonal Ba₅Ta₄O₁₅ (Ba₅Nb₄O₁₅) end members. 16,27-30 For example, in the BaO-ZnO-Ta2O5 system these include 8-layer 'twin'-type hexagonal Ba₈ZnTa₆O₂₄ and 10-layer hexagonal Ba₁₀Zn_{0.25}Ta_{7.9}O₃₀ phases,²⁸ whereas in the BaO-CoO-Nb2O5 system an 8-layer 'shift'-type hexagonal Ba₈CoNb₆O₂₄ has been identified.²⁹ Remarkably, we were not able to synthesize an 8-layer hexagonal Ba₈MgTa₆O₂₄ phase in the BaO-MgO-Ta₂O₅ system in agreement with earlier reports by Mallinson et al. 16 and Kawaguchi et al. 30 The X-ray analysis of the compound with the Ba₈MgTa₆O₂₄ target composition sintered at 1450 °C revealed a mixture of Ba₃MgTa₂O₉ and Ba₅Ta₄O₁₅ phases. The same target compound equilibrated at 1600 °C resulted in a mixture of cubic Ba₃MgTa₂O₉ and 10-layer (10L) hexagonal Ba₁₀Mg_{0.25}Ta_{7.9}O₃₀ perovskite in agreement with ref. 16.

The Ta-rich region of the BaO-Ta₂O₅ binary has been recently revised by Vanderah et al. 31 during a comprehensive study of the BaO-TiO₂-Ta₂O₅ ternary system. In contrast to the earlier report,³² the authors of ref. 31 have found that three TTB related phases with extended solid solution exist within the $26 \le \text{BaO} \le$ 43 mol% range. To avoid oxygen deficiency,31 these phases have been formulated as $Ba_xTa_{(10-2x)/5}[Ta_{10}O_{30}]$ where $3.40 \le x \le$ 3.93 (space group P4bm), $Ba_y Ta_{(14-2y)/5} [Ta_{22}O_{62}]$ where $5.11 \le y$ \leq 6.77 (space group P4bm) and Ba_zTa_{(18-2z)/5}[Ta₃₄O₉₄] where

Table 1 Lattice parameters of the TTB-type 9:1:7 phase solid solution $Ba_{9+1.5x}Mg_{1+x}Ta_{14-x}O_{45}$ refined within the *P4/mbm* space group. The pattern (R_p) and weighted pattern (R_{wp}) are reliability factors of the Rietveld refinement

x value	Composition [mol BaO:MgO:Ta ₂ O ₅]	Secondary phases [weight %]	a [Å]	c [Å]	Vol [ų]	R _p [%]	$R_{ m wp}$ [%]
-0.725	50.93:1.77:47.31	hex-BaTa ₂ O ₆ [32%]	12.588(4)	3.957(8)	627.1(9)	8.12	11.37
-0.367	51.96:3.89:44.15		12.598(1)	3.961(4)	628.7(2)	5.21	7.06
0	52.94:5.88:41.18		12.625(5)	3.972(0)	633.1(6)	4.55	5.93
0.645	54.72:9.03:36.26	$Ba_3MgTa_2O_9$ [15%]	12.630(5)	3.977(0)	634.4(5)	5.84	7.43

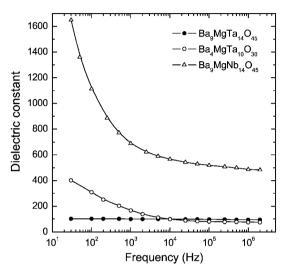


Fig. 2 Room temperature frequency dependence of the dielectric constant of $Ba_9MgTa_{14}O_{45}$, $Ba_4MgTa_{10}O_{30}$ and $Ba_9MgNb_{14}O_{45}$ ceramics of 97–98% density.

6.17 $\leq z \leq 7.42$ (space group *Pbam*). The ability of these TTB related phases to incorporate substantial amount of foreign ions was demonstrated in the example of the BaO–TiO₂–Ta₂O₅ system, where the TTB phases extend into the ternary region and dissolve up to 12 mol% of TiO₂.³¹ Our analysis of the similar composition region in the BaO–MgO–Ta₂O₅ system confirmed the existence of the TTB-related phases along the BaO–Ta₂O₅ binary. Moreover, we have found that these phases slightly extend into the ternary region by dissolving up to 1.5–2.0 mol% of MgO. In this case, much lower solubility of MgO as compared to TiO₂ is not unexpected. Assuming that Mg²⁺(Ti⁴⁺) substitutes Ta⁵⁺, the charge compensation of the Mg_{Ta}^{m} defects would require 3 times more oxygen vacancies than that required for compensation of the Ti_{Ta} defects. A high concentration of oxygen vacancies will eventually destabilize the TTB crystal structure.

Another ternary phase with a close relationship to the tungsten bronze type structure is 4:1:5 $Ba_4MgTa_{10}O_{30}$ (space group Amm2, a=3.90, b=10.22, c=14.97 Å). It forms along the $MgTa_2O_6$ – $BaTa_2O_6$ join and it is isostructural with $Ba_4Co-Ta_{10}O_{30}$ and $Ba_4NiTa_{10}O_{30}$. ¹⁸

Although both 9:1:7 $Ba_9MgTa_{14}O_{45}$ and 4:1:5 $Ba_4MgTa_{10}O_{30}$ phases have been known for a number of years, their dielectric properties have not been reported so far. Fig. 2 shows the frequency dependence of the dielectric constant of $Ba_9MgTa_{14}O_{45}$ and $Ba_4MgTa_{10}O_{30}$ ceramics. For comparison, we have also prepared and measured a $Ba_9MgNb_{14}O_{45}$ ceramic that is

isostructural with Ba₉MgTa₁₄O₄₅. We find that the room temperature dielectric constant of Ba₉MgTa₁₄O₄₅ shows a value of 98–99 without any noticeable frequency dispersion. Moreover, the dielectric loss of this compound was below the detection limit of the LCR Meter (i.e., $\tan \delta < 0.002$). Providing a temperature stable dielectric constant, the Ba₉MgTa₁₄O₄₅ compound with TTB structure may find technical applications as a compact dielectric resonator for the 1-2 GHz range. In contrast to Ba₉MgTa₁₄O₄₅, its Nb analogue shows a rather large dielectric constant ($\varepsilon' \approx 1200$ at 100 Hz) with a very strong frequency dependence and large dielectric loss (e.g., $\tan \delta \approx 0.05$ at 2 MHz), consistent with typical ferroelectric relaxor behavior. The dielectric constant of Ba₄MgTa₁₀O₃₀ has a noticeable frequency dependence below 100 kHz. At higher frequency, ϵ' of Ba₄Mg-Ta₁₀O₃₀ levels off at around 79. The low frequency dispersion of ε' may be associated with a slow ionic conductivity or with a possible ferroelectric ground state. To clarify these assumptions, a detailed temperature characterization of dielectric properties is under way.

In conclusion, we have studied the phase equilibrium in the ternary BaO-MgO-Ta₂O₅ composition field. We confirmed only three ternary compounds (i.e., Ba₃MgTa₂O₉, Ba₉MgTa₁₄O₄₅ and Ba₄MgTa₁₀O₃₀) that form upon equilibration at 1450 °C. We found no evidence of the hexagonal Ba₉Mg₄Ta₂₀O₆₃ phase, ¹⁷ nor can we confirm the existence of the Ba₇Ta₆O₂₂ phase reported in ref. 19. TTB-type Ba₉MgTa₁₄O₄₅ forms along the BaTa₂O₆-Ba₃MgTa₂O₉ join. We found that only the hexagonal polymorph of the BaTa2O6 phase exists along the Mg4Ta2O9-BaTa2O6 tie line. We also found that the MgO solubility in the TTB-like $Ba_4Ta_{10}O_{29}$, $BaTa_4O_{11}$ and $Ba_{6.63}Ta_{34.95}O_{95}$ is less than 2.0 mol%. For the first time we have reported the dielectric properties of the Ba₉MgTa₁₄O₄₅ and Ba₄MgTa₁₀O₃₀ phases and found that the TTB Ba₉MgTa₁₄O₄₅ shows a promising combination of relatively large dielectric constant and low dielectric loss which makes it an attractive candidate for passive microwave devices.

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